

Switchmode Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 150°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, free-wheeling and polarity protection diodes.

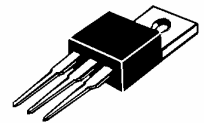
Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * 175°C Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- * *In compliance with EU RoHs 2002/95/EC directives*
- * Mounting Torque: 5 in-lbs.Max.

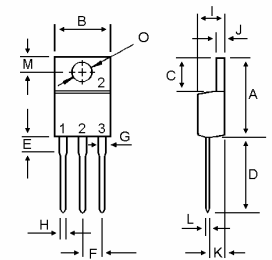


SCHOTTKY BARRIER RECTIFIERS

**20 AMPERES
100 VOLTS**



TO-220AB



DIM	MILLIMETERS	
	MIN	MAX
A	14.68	15.32
B	9.78	10.42
C	5.02	6.52
D	13.06	14.62
E	3.57	4.07
F	2.42	2.66
G	1.12	1.36
H	0.72	0.96
I	4.22	4.98
J	1.14	1.38
K	2.20	2.98
L	0.33	0.55
M	2.48	2.98
O	3.70	3.90

MAXIMUM RATINGS

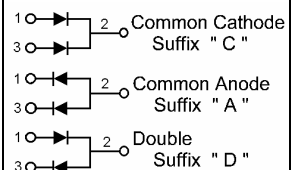
Characteristic	Symbol	S20T100CB	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	100	V
RMS Reverse Voltage	$V_{R(RMS)}$	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),	$I_{F(AV)}$	10 20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I_{FSM}	315	A
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +150	°C

THERMAL RESISTANCES

Typical Thermal Resistance junction to case (per device)	$R_{\theta j-c}$	3.4	°C/w
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ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	Min	Typ.	Max.	Unit
Maximum Instantaneous Forward Voltage (per diode) ($I_F = 0.1$ Amp $T_C = 25^\circ C$) ($I_F = 5.0$ Amp $T_C = 25^\circ C$) ($I_F = 10$ Amp $T_C = 25^\circ C$)	V_F	---	0.31 0.50 0.59	0.32 0.52 0.61	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^\circ C$) (Rated DC Voltage, $T_C = 125^\circ C$)	I_R	--	0.03 9	0.05 12	mA



S20T100CB

FIG-1 FORWARD CURRENT DERATING CURVE

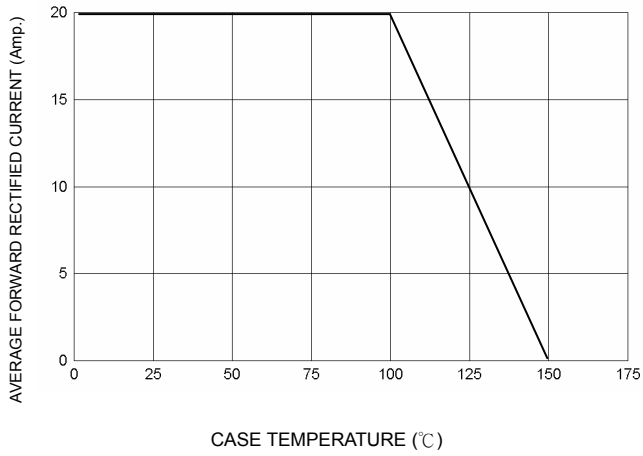


FIG-2 TYPICAL FORWARD CHARACTERISTICS

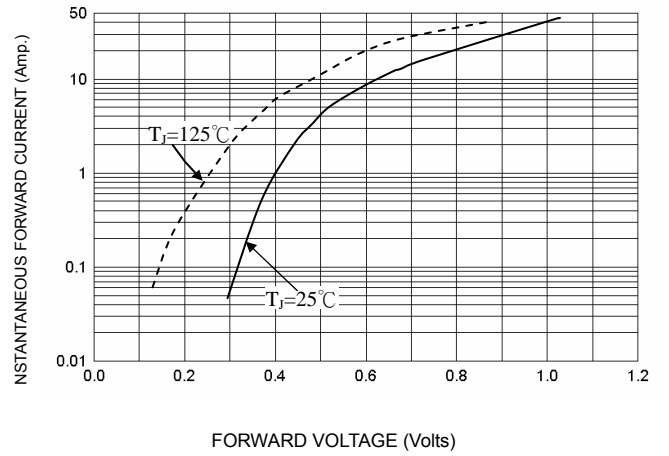


FIG-3 TYPICAL REVERSE CHARACTERISTICS

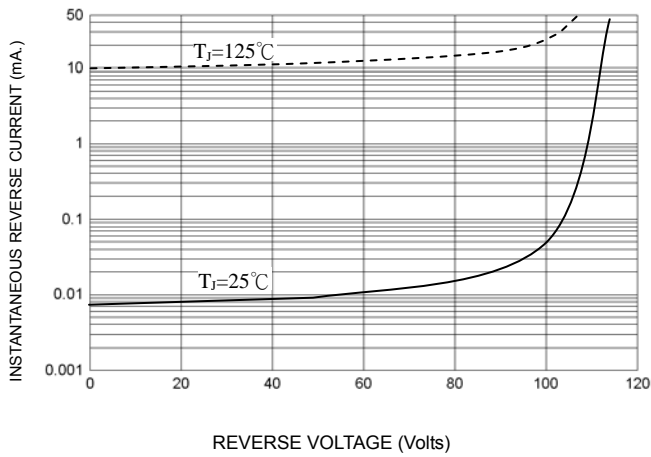


FIG-4 TYPICAL JUNCTION CAPACITANCE

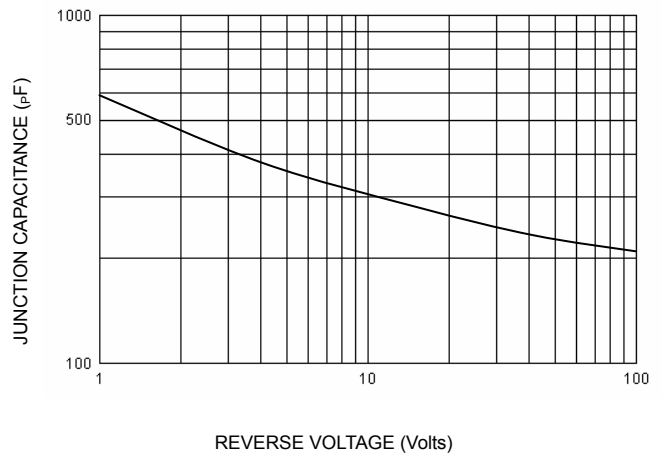


FIG-5 PEAK FORWARD SURGE CURRENT

